NSN 5961-01-220-9916

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-220-9916 **Inclosure Material:** Metal **Overall Length:** 2.627 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** 1.063 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 repetitive peak off-state voltage and 400.0 repetitive peak reverse voltage and 480.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 110.00 amperes forward current, total rms horsepower metric **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0